



18W  
B

Docket No.: M4065.0971/P971  
(PATENT)

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of:  
Luan C. Tran

Application No.: 10/663,710

Confirmation No.: 2238

Filed: September 17, 2003

Art Unit: 2818

For: METHOD OF FORMING DRAM ACCESS  
TRANSISTORS (AS AMENDED)

Examiner: T. T. V. Ho

**AMENDMENT UNDER 37 C.F.R. §1.312**

MS AF  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

Prior to the issuance of the above-identified U.S. patent application, please  
replace the current title with the following new title:

**METHOD OF FORMING DRAM ACCESS TRANSISTORS**